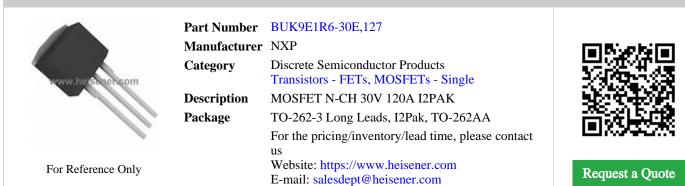


BUK9E1R6-30E,127

BUK9E1R6-30E,127 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BUK9E1R6-30E,127 Specifications

Manufacturer Part Number	BUK9E1R6-30E,127
Manufacturer	NXP
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-262-3 Long Leads, I2Pak, TO-262AA
Series	TrenchMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	120A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	5V, 10V
Vgs(th) (Max) @ Id	2.1V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	113nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	16150pF @ 25V
Vgs (Max)	±10V
FET Feature	-
Power Dissipation (Max)	349W (Tc)
Rds On (Max) @ Id, Vgs	1.4 mOhm @ 25A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	I2PAK
Package / Case	TO-262-3 Long Leads, I2Pak, TO-262AA
	Report errors?

BUK9E1R6-30E,127 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE ELARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

BUK9E1R6-30E,127 Payment Methods



BUK9E1R6-30E,127 Shipping Methods



If you have any question about BUK9E1R6-30E,127, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com